

Dong-Hwan Kim

List of Publications by Year in descending order

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3
papers

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2682572

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2550090

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3
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citing authors

#	ARTICLE	IF	CITATIONS
1	Ka-Band MMIC Using AlGaIn/GaN-on-Si With Recessed High- Dual MIS Structure. IEEE Electron Device Letters, 2018, 39, 995-998.	3.9	10
2	V-band monolithic microwave integrated circuit with continuous wave output power of >23.5 dBm using conventional AlGaIn/GaN-on-Si structure. Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics, 2016, 34, 040602.	1.2	4
3	Thermal stability and small-signal characteristics of AlGaIn/GaN HEMTs with gate insertion metal layer for millimeter-wave applications. Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics, 2017, 35, .	1.2	1